PRELIMINARY DATA

23-STAGE COUNTER

- **LOW** QUIESCENT POWER DISSIPATION
- WIDE SUPPLY VOLTAGE RANGE: 3 to 17V
- FULLY PROTECTED INPUTS
- INVERTER AVAILABILITY FOR CRYSTAL OSCILLATOR TIMING APPLICATION
- ADJUSTABLE FREQUENCY DIVIDER IN 127 STEPS
- TEST OUTPUT AVAILABLE
- MOTOR DRIVE STAGE OUTPUT

The M730 (standard temperature range) is a 23 stage binary counter in COS/MOS technology in a single **monolithic** chip. An inverter is available for crystal oscillator application in which the function of the **trimmer** capacitor has been taken over by the variable frequency divider comprised in the IC and used to **set** the correct output frequency. For this purpose, seven adjustment terminals are provided on the M730: they are used to set the divider ratio to the required value with an accuracy of 10^{-6} . The adjustable frequency divider has been designed in such a way that the maximum output frequency is set when all **adjustment** terminals are either open-circuit or connected to pin 14. If one or more adjustment terminals **are** grounded (taken to pin 13), the output frequency decreases. The by-four-divided oscillator frequency **may** be checked at a separate test output (pin 8) non-reactive with respect to the oscillator. Based on **this check** the output frequency and consequently the accuracy of the clock may be adjusted at the terminal 1 to 7 by means of the variable frequency divider. With an oscillator frequency of 4.194812 MHz, the series-connected push-pull output stage supplies a symmetrical square wave signal with a pulse duty factor of 0.5 and a repetition frequency of 0.5 Hz if the variable frequency divider is set to its medium **value**. The device is available in 14 lead dual in-line plastic or ceramic package.

ABSOLUTE MAXIMUM RATINGS*

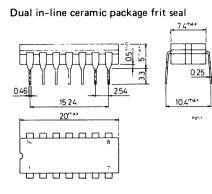
V _{DD} **	Supply voltage	-0.3 to	+17	v
1 ₁₁	Output current		60	mΑ
P _{tot}	Power dissipation at $T_{amb} = 25^{\circ}C$		200	mW
Top	Operating temperature range	-40 to	+85	°C
T _{stg}	Storage temperature range	-55 to +	125	°C

* Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other condition above those indicate in the "Recommended operating conditions" section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

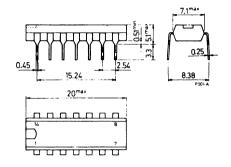
** All voltages are with respect to V_{SS} (GND).

DRDERING NUMBERS: M730 B1 for dual in-line plastic package M730 D1 for dual in-line ceramic package frit seal

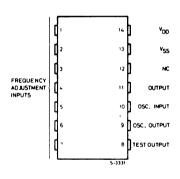
MECHANICAL DATA (dimensions in mm)



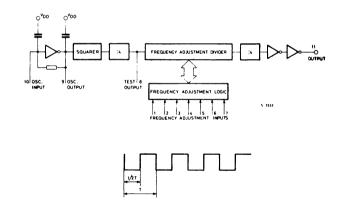
Dual in-line plastic package



PIN CONNECTIONS



BLOCK DIAGRAM and OUTPUT WAVEFORM



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RECOMMENDED OPERATING CONDITIONS

VDD	Supply voltage: for general applications	3 to 16.5	v
	for oscillator starting	6 to 16.5	v
Vi	Input voltage	V _{DD} to V _{SS}	v
I ₁₁	Output current	40	mA
Top	Operating temperature	-40 to +85	°C

STATIC ELECTRICAL CHARACTERISTICS (over recommended operating conditions)

		Test conditions			Values									
	Parameter			V _{DD} (V)	-40° C			25° C			85°C			Unit
			V ₀ (V)		Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Typ.	Max.	
v _{он}	Output high voltage	I _{ОН} = 0		6	5.99			5.99	6		5.95			v
				12	11.99			11.99	12		11.95			
Vol	Output low voltage	I _{OL} = 0		6			0.01		0	0.01			0.05	v
				12			0.01		0	0.01			0.05	
I _{DN}	Output drive		2	6	21			20	25		13			mA
	current N-channel		2	12	34			33	40		22			
I _{DP}	Output drive		4	6	21			20	25		13			mA
	current P-channel		10	12	34			33	40		22			
ION	Current consump.	1 _O = 0*		12					3					mA

* At quartz frequency of 4.194.812 Hz.

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DYNAMIC ELECTRICAL CHARACTERISTICS (T_{amb} = 25°C, quartz frequency 4.194.812 Hz)

Parameter		Test conditions	Values							
			V _{DD} (V)	M730 D1 type			M730 B1 type			Unit
				Min.	Тур.	Max.	Min.	Тур.	Max.	1
f⊤	Frequency test output		12	1.048703			1.048703			Hz
fo**	Output frequency		12		0.5			0.5		Hz
∆f _o f _o	Range output frequency adjustment		12		± 121			± 121		ppm
Ro	Output resistance	R _L = 300Ω	12			100			100	Ω

* At the centre position of the variable divider.

APPLICATION CIRCUIT

